

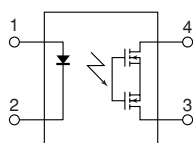
NAIS

**Super miniature design,
SOP(1 Form A) 4-pin type
Controls load voltage 60V,
350V, 400V**

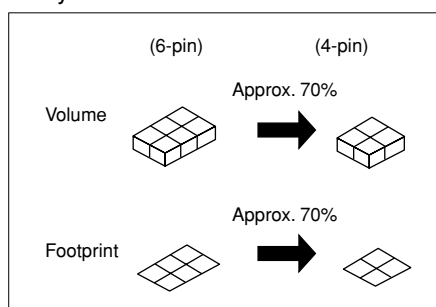
GU PhotoMOS (AQY210S)



mm inch



(W)4.3 × (L)4.4 × (H)2.1 mm (W).169 × (L).173 × (H).083 inch —approx. 70% of the volume and 70% of the footprint size of SO package 6-pin type PhotoMOS Relays.



3. Controls low-level analog signals
PhotoMOS relays feature extremely low closed-circuit offset voltage to enable control of low-level analog signals without distortion.

4. Low-level off state leakage current
In contrast to the SSR with an off state leakage current of several milliamperes, the PhotoMOS relay features a very small off state leakage current of typ. 100 pA (AQY214S) even with the rated load voltage of 400 V.

FEATURES

1. SO package 4-Pin type in super miniature design

The device comes in a super-miniature SO package 4-Pin type measuring

2. Tape and reel

The device comes standard in a tape and reel (1,000 pcs./reel) to facilitate automatic insertion machines.

TYPICAL APPLICATIONS

- Telecommunications (PC, Electronic Notepad)
- Measuring and Testing equipment
- Factory Automation Equipment
- Security equipment
- High speed inspection machines

TYPES

AC/DC type

Output rating*		Part No.		Packing quantity in tape and reel
Load voltage	Load current	Picked from the 1/2-pin side	Picked from the 3/4-pin side	
60 V	500 mA	AQY212SX	AQY212SZ	1,000 pcs.
350 V	120 mA	AQY210SX	AQY210SZ	
400 V	100 mA	AQY214SX	AQY214SZ	

* Indicate the peak AC and DC values.

Notes: (1) Tape package is the standard packing style. Also available in tube. (Part No. suffix "X" or "Z" is not needed when ordering; Tube: 100 pcs.; Case: 2,000 pcs.)

(2) For space reasons, the top two letters of the product number "AQY" and "S" are omitted on the product seal. The package type indicator "X" and "Z" are omitted from the seal. (Ex. the label for product number AQY210S is 210).

RATING

AC/DC type

1. Absolute maximum ratings (Ambient temperature: 25°C 77°F)

Item		Symbol	AQY212S	AQY210S	AQY214S	Remarks
Input	LED forward current	I _F	50 mA			
	LED reverse voltage	V _R	5 V			
	Peak forward current	I _{FP}	1 A			f = 100 Hz, Duty factor = 0.1%
	Power dissipation	P _{in}	75 mW			
Output	Load voltage (peak AC)	V _L	60 V	350 V	400 V	
	Continuous load current (peak AC)	I _L	0.5 A	0.12 A	0.1 A	
	Peak load current	I _{peak}	1.5 A	0.3 A	0.24 A	100ms (1 shot), V _L = DC
	Power dissipation	P _{out}	300 mW			
Total power dissipation		P _T	350 mW			
I/O isolation voltage		V _{iso}	1,500 V AC			
Temperature limits	Operating	T _{opr}	-40°C to +85°C -40°F to +185°F			Non-condensing at low temperatures
	Storage	T _{stg}	-40°C to +100°C -40°F to +212°F			

GU PhotoMOS (AQY210S)

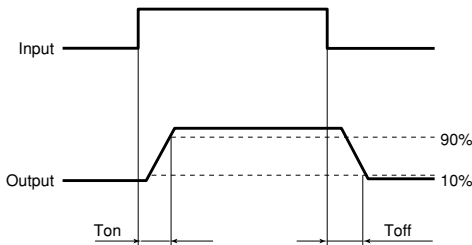
2. Electrical characteristics (Ambient temperature: 25°C 77°F)

Item		Symbol	AQY212S	AQY210S	AQY214S	Remarks
Input	LED operate current	Typical	0.9 mA			I _L = Max.
		Maximum	3 mA			
	LED turn off current	Minimum	0.4 mA			I _L = Max.
		Typical	0.85 mA			
LED dropout voltage	Typical	1.25 V (1.14 V at I _F = 5 mA)			I _F = 50 mA	
	Maximum	1.5 V				
Output	On resistance	Typical	0.83 Ω	17 Ω	25 Ω	I _F = 5 mA I _L = Max. Within 1 s on time
		Maximum	2.5 Ω	25 Ω	35 Ω	
	Off state leakage current	Maximum	1 μA			I _F = 0 mA V _L = Max.
Transfer characteristics	Turn on time*	Typical	0.65 ms	0.23 ms	0.21 ms	I _F = 5 mA I _L = Max.
		Maximum	2 ms	0.5 ms	0.5 ms	
	Turn off time*	Typical	0.04 ms			I _F = 5 mA I _L = Max.
		Maximum	0.2 ms			
	I/O capacitance	Maximum	1.5 pF			f = 1 MHz V _B = 0 V
Initial I/O isolation resistance	Minimum	1,000 MΩ			500 V DC	

Note: Recommendable LED forward current I_F = 5mA.

For type of connection

*Turn on/Turn off time

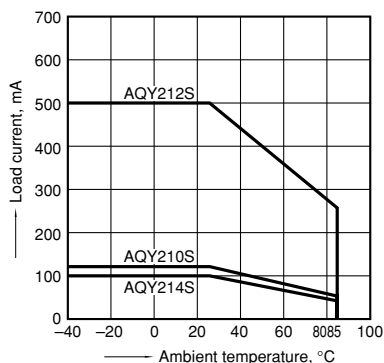


- For Dimensions
- For Schematic and Wiring Diagrams
- For Cautions for Use

REFERENCE DATA

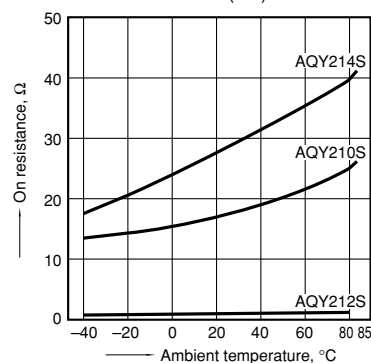
1. Load current vs. ambient temperature characteristics

Allowable ambient temperature: -40°C to +85°C
-40°F to +185°F



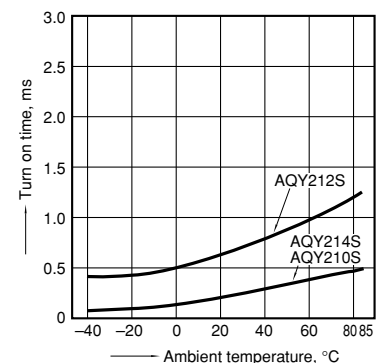
2. On resistance vs. ambient temperature characteristics

Measured portion: between terminals 3 and 4;
LED current: 5 mA; Load voltage: Max. (DC);
Continuous load current: Max. (DC)



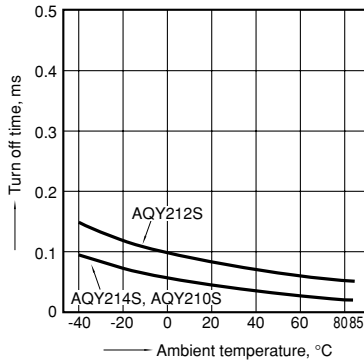
3. Turn on time vs. ambient temperature characteristics

LED current: 5 mA; Load voltage: Max. (DC);
Continuous load current: Max. (DC)



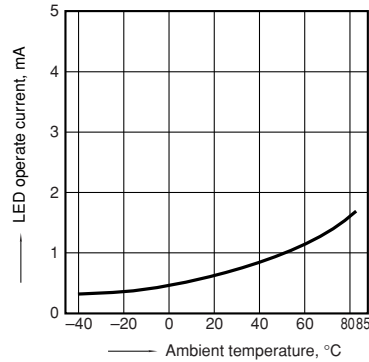
4. Turn off time vs. ambient temperature characteristics

LED current: 5 mA; Load voltage: Max. (DC);
Continuous load current: Max. (DC)



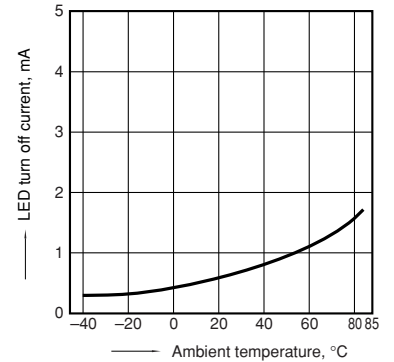
5. LED operate current vs. ambient temperature characteristics

Sample: All types; Load voltage: Max. (DC);
Continuous load current: Max. (DC)



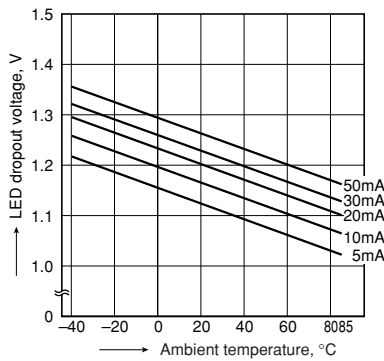
6. LED turn off current vs. ambient temperature characteristics

Sample: All types; Load voltage: Max. (DC);
Continuous load current: Max. (DC)



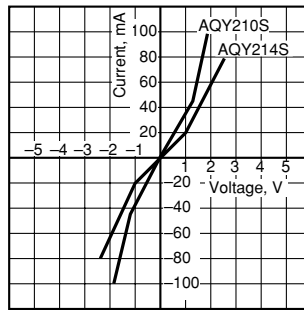
7. LED dropout voltage vs. ambient temperature characteristics

Sample: All types; LED current: 5 to 50 mA



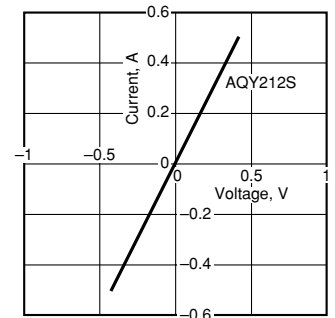
8-(1). Current vs. voltage characteristics of output at MOS portion

Measured portion: between terminals 3 and 4;
Ambient temperature: 25°C 77°F



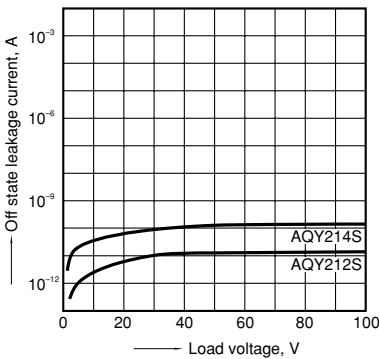
8-(2). Current vs. voltage characteristics of output at MOS portion

Measured portion: between terminals 3 and 4;
Ambient temperature: 25°C 77°F



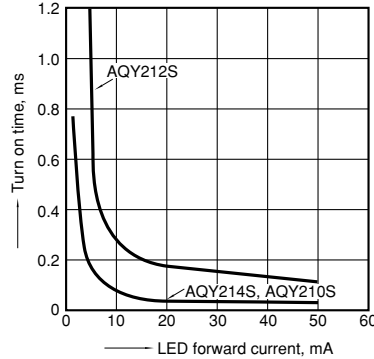
9. Off state leakage current vs. load voltage characteristics

Measured portion: between terminals 3 and 4;
Ambient temperature: 25°C 77°F



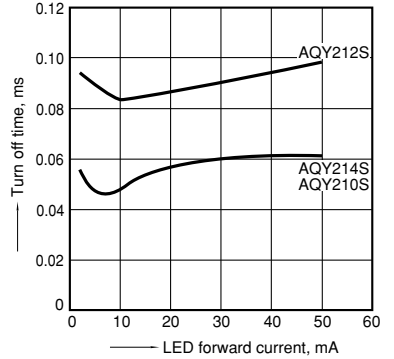
10. Turn on time vs. LED forward current characteristics

Measured portion: between terminals 3 and 4;
Load voltage: Max. (DC); Continuous load current: Max. (DC); Ambient temperature: 25°C 77°F



11. Turn off time vs. LED forward current characteristics

Measured portion: between terminals 3 and 4;
Load voltage: Max. (DC); Continuous load current: Max. (DC); Ambient temperature: 25°C 77°F



12. Output capacitance vs. applied voltage characteristics

Measured portion: between terminals 3 and 4;
Frequency: 1 MHz; Ambient temperature: 25°C 77°F

